

Development of a BiVO₄/WO₃ system by plasma magnetron sputtering for photoelectrochemical water splitting

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Bismuth vanadate (BiVO₄) is one of the visible-light driven photocatalysts that has been widely studied in the last years [1, 2]. However, the actual conversion efficiency achieved with BiVO₄ photoanodes is considerably less than the theoretical values because of some drawbacks such as poor electron mobility and slow kinetics of water oxidation. In these respects, the formation of a heterojunction photoanode coupling tungsten oxide (WO₃) is a very promising way in order to achieve better charge separation and thus higher overall performances. In this work we report on a deposition by plasma magnetron sputtering of a BiVO₄/WO₃ system from a previously studied bilayer WO₃ n–n heterojunction [3]. Various parameters such as film thickness and stoichiometry were optimized to improve the efficiency of the heterojunction.

Preliminary photoelectrochemical (PEC) performances in water splitting were evaluated in a homemade three-electrode cell under AM 1.5G simulated solar light irradiation. The results confirm an enhanced PEC activity of the heterojunction photoanodes compared to individual materials.

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[3] G. L. Chiarello, M. Bernareggi, M. Pedroni, M. Magni, S. M. Pietralunga, A. Tagliaferri, E. Vassallo, E. Selli, Enhanced photopromoted electron transfer over a bilayer WO₃ n–n heterojunction prepared by RF diode sputtering, J. Mater. Chem. A 5, (2017) 12977–12989.